

HINTS & SOLUTIONS

EXERCISE - 1
Single Choice

1. **Unit cell** : Unit cell is the smallest portion of a crystal lattice which, when repeated in different directions, generates the entire lattice.

4. In Bravais lattices, each point has identical surroundings.

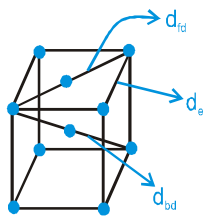
5. For rhombohedral system, axial distance and axial angles are $a = b = c$, $\alpha = \beta = \gamma \neq 90^\circ$

6. Distance between two nearest neighbours in bcc = $\frac{\sqrt{3}a}{2}$
 $= \frac{\sqrt{3} \times \sqrt{2}}{2} = \frac{1.732 \times \sqrt{2}}{2} = 4.503 \text{ \AA}$

8. $d_e = a$

$$d_{fd} = \sqrt{2}a$$

$$d_{bd} = \frac{\sqrt{3}a}{2} \therefore d_{fd} > d_e > d_{bd}$$



11.

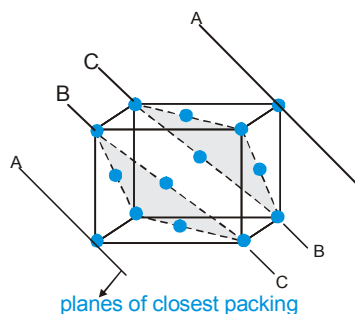
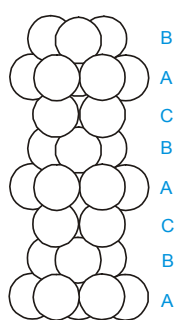


12. In ABB ABBB A, there is no close packing as there are repeated planes adjacent to each other.

13. $4r = a\sqrt{2}$

$$a = \frac{4r}{\sqrt{2}} = \frac{4 \times 1.28}{\sqrt{2}} \text{ \AA} = 3.62 \text{ \AA}$$

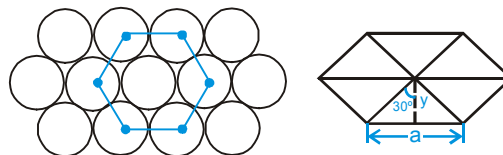
16.



19. No. of tetrahedral voids = $8 \times \frac{1}{8} = 1$

No. of Octahedral voids = $1 \times 1 = 1$ (at body center).

20. **Volume of hexagon** :



$$\tan 30^\circ = \frac{a}{2 \times y} \quad \text{So } y = \frac{a \times \sqrt{3}}{2 \times 1} = \frac{\sqrt{3}}{2} a \quad \text{and Area}$$

$$\text{of hexagonal surface} = 6 \left[\frac{1a}{2} \times \frac{\sqrt{3}a}{2} \right] = \frac{6\sqrt{3}a^2}{4}$$

volume of hexagon = area of base \times height

$$= \frac{6\sqrt{3}}{4} \times a^2 \times 2 \sqrt{\frac{2}{3}} a = \frac{6\sqrt{3}}{4} \times (2r)^2 + 2 \sqrt{\frac{2}{3}} \times (2r) = 24\sqrt{2} r^3$$

22. No. of A atoms = 6.

No. of C atoms = $6 \times \frac{2}{3} = 4$.

\therefore Formula = C_4A_6 or C_2A_3 .

25. Coordination number of Zn^{2+} ion in Zinc blende = 4.

Zn^{2+} ion present in half of tetrahedral void formed by S^{2-} in fcc unit cells.

27. $A \rightarrow \frac{1}{8} \times 8 = 1$, $B \rightarrow 4 \times \frac{1}{2} = 2$ and $O^{2-} = 4$ so formula of spinel = AB_2O_4

29. In rock salt structure, Cl^- forms fcc (ccp) lattice & Na^+ occupies octahedral voids, So tetrahedral voids are vacant.

32. On increasing temp^r C.N. decreases.

\therefore CsCl (8 : 8) structure changes into (6 : 6) NaCl type structure.

33. Since Ag^+ (cation) is smaller than Cl^- (anion) & hence cation is present in voids.

In CaF_2 , F_{anion}^- is smaller.

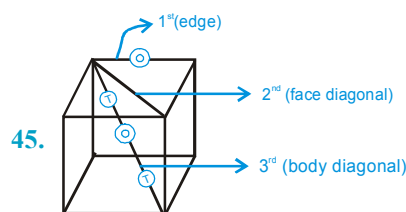
35. p-type semiconductors acquired positive charge because p-type semiconductor have holes due to presence of 13 group elements in 14 group elements.

37. $X = 7 \times \frac{1}{8} = \frac{7}{8}$; $Y = \frac{1}{2} \times 6 = 3$; $Z = \frac{1}{8}$.
 $\Rightarrow X_{7/8} Y_3 Z_{1/8} = X_7 Y_{24} Z$



43. For (bcc) $r^+/r^- = 0.732$ and $a = \frac{2(r^+ + r^-)}{\sqrt{3}}$
 and diameter of cubical void $(2r^+) = a(\sqrt{3} - 1)$
 $= 2.888 \times 0.732 = 2.108 \text{ \AA}$.

44. no. of oxide ions = 4
 no. of A particles = $\frac{1}{6} \times 8 = \frac{4}{3}$
 no. of B particles = $\frac{1}{3} \times 4 = \frac{4}{3}$
 so formula is $A_{4/3} B_{4/3} O_4$ or ABO_3 .

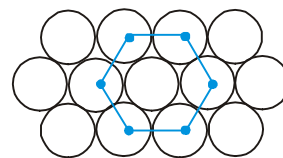


47. Cu_4 Ag_3
 \downarrow \downarrow
 Froms c.c.p., $\frac{3}{8}$ th of tetrahedral voids,
 $z = 4$
 Au
 \downarrow
 $\frac{1}{4}$ of Octahedral voids [\therefore No. of O- voids = 4]
 [\therefore No. of T- voids = 8].

50. Distance between nearest neighbours is along the face diagonal = $\frac{a\sqrt{2}}{2}$.

51. Density = $\frac{Z \times M}{N_A \times a^3} = \frac{4 \times 195}{6.02 \times 10^{23} \times (3.9231 \times 10^{-8})^3}$
 $= 21.86 \text{ g/cm}^3$
 for fcc lattice, $4r = a\sqrt{2}$
 so, $r = \frac{a\sqrt{2}}{4} = \frac{3.9231\sqrt{2}}{4} \text{ \AA} = 1.387 \text{ \AA}$.

53. Number of nearest neighbours in hcp pattern in its own layer = 6.



56. It is fluorite (CaF_2) structure. Since formula is AB_2
 \Rightarrow No. of B atoms is twice the no. of A atoms. Hence B occupies all the tetrahedral voids (100%).
 AB_2 is (8 : 4) compound (Fluorite Structure Compound)
 \downarrow \downarrow
 C.N. of A C.N. of B.

60. $(r_{Rb^+} + r_{Cl^-}) + (r_{K^+} + r_{Br^-}) - (r_{K^+} + r_{Cl^-}) = (r_{Rb^+} + r_{Br^-})$
 $3.285 + 3.293 - 3.139 = 3.439$.

63. Some of O^{2-} combine with each other forming O_2 gas which is liberated leaving behind electrons at the site vacated by oxide ions.

65. $Na = 1 \times 1 = 1$
 $W = 8 \times \frac{1}{8} = 1 \Rightarrow NaWO_3$
 $O = 12 \times \frac{1}{4} = 3$.

66. Number of F atom in metal fluoride = $\frac{1}{8} \times 8 = 1$.
 Number of M atom in metal fluoride = $1 \times 1 = 1$.
 So formula of metal fluoride = MF.

67. $r_+ + r_- = \frac{\sqrt{3}a}{2} = \frac{\sqrt{3} \times 4.3}{2} = 3.72 \text{ \AA}$

68. Coordination number of square packing pattern is 4.

69. for X, $8 \times \frac{1}{8} = 1$; for Y, $6 \times \frac{1}{2} = 3$
 so, XY_3

70. No. of X atom per unit cell = $7 \times \frac{1}{8} = \frac{7}{8}$
 No. of Y atom per unit cell = $6 \times \frac{1}{2} = 3$
 \therefore Formula = $X_{7/8} Y_3$ or $X_7 Y_{24}$.

71. CsCl compound has bcc arrangement. Cl^- ion forms cubic lattice and Cs^+ ion occupied at body center of unit cell.

72. Density of crystalline CsCl = 3.988 g/cc then,

$$d = \frac{d \times M_{\text{CsCl}}}{N_A \times (a)^3}$$

$$\begin{aligned} \text{Volume of unit cell } (a)^3 &= \frac{Z \times M_{\text{CsCl}}}{N_A \times d} \\ &= \frac{1 \times (132.9 + 35.5)}{6.023 \times 10^{23} \times 3.988} = 7.01 \times 10^{-23} \text{ cm}^3. \end{aligned}$$

73. Radius ratio Types of structure Coordination

		No.
$r_+/r_- < 0.155$	linear void	2
$0.155 \leq r_+/r_- < 0.225$	triangular void	3
$0.225 \leq r_+/r_- < 0.414$	tetrahedral void	4
$0.414 \leq r_+/r_- < 0.732$	octahedral void	6
$0.732 \leq r_+/r_- < 1$	cubical void	8

74. $a = 2\sqrt{2} r$

$$\therefore v = a^3 = 16\sqrt{2} r^3 = 16 \times \sqrt{2} \times (2 \times 10^{-8})^3 = 1.8 \times 10^{-22} \text{ cm}^3$$

75. When all particle along one body diagonal are removed, these 2 X particles from corner are removed, one Y particle removed & 2 Z particle removed.

$$\text{Hence new arrangement, X particle} = \frac{1}{8} \times 6 + \frac{1}{2} \times 6 = \frac{15}{4}$$

Y particle = 3 ; Z particle = 6

$$\text{Hence formula} = X_{15/4} Y_3 Z_6 = X_{5/4} Y Z_2 = X_5 Y_4 Z_8$$

76. In new arrangement, A particles

$$= \left(\frac{1}{8} \times 8 + \frac{1}{2} \times 6 \right) - \left(\frac{1}{8} \times 4 + \frac{1}{2} \times 2 \right) = \frac{5}{2}$$

$$\text{\& B particles} = \left(\frac{1}{4} \times 12 + 1 \right) - \left(1 + \frac{1}{4} \times 2 \right) = \frac{5}{2}$$

So, formula is AB.

77. for tetrahedral voids $\frac{r}{R} = 0.225$

$$\Rightarrow \text{for octahedral voids } \frac{r}{R} = 0.414$$

78. $d_{1-2} = \frac{\sqrt{2}a}{2} = \frac{a}{\sqrt{2}}$; $d_{2-3} = \sqrt{\left(\frac{a}{2}\right)^2 + \left(\frac{a}{2}\right)^2} = \frac{a}{\sqrt{2}}$

Hence $d_{1-2} = d_{2-3}$.

79. According to figure, it shows a simple cubic lattice. Now observe the center atom, its has 6 nearest neighbours.

80. Perimeter of plane is $= 2C + 8R = \frac{2 \times 4\sqrt{2}R}{3} + 8R = 6.437R$

81. Ionic solid having C.N. = 6 cation in octahedral holes.

$$\text{Hence, } 0.414 < \left(\frac{r_+}{r_-} \right) < 0.732.$$

82. For ZnS $\Rightarrow 4(r_{\text{Zn}^{2+}} + r_{\text{S}^{2-}}) = \sqrt{3} a.$

$$a = \frac{4(r_{\text{Zn}^{2+}} + r_{\text{S}^{2-}})}{\sqrt{3}} \Rightarrow a = 4 \frac{(0.83 + 1.74)}{1.732} = 5.93 \text{ \AA}.$$

83. Ferromagnetic substances can be magnetised permanently.

84. Refer NaCl (Rock salt structure).

85. $Z = 4, M = 60$

$$60 \times 4 \text{ gram} \text{ ————— } 6.023 \times 10^{23} \text{ unit cells}$$

$$1 \text{ gram} \text{ ————— } \frac{6.02 \times 10^{23}}{60 \times 4} = 2.5 \times 10^{21}$$

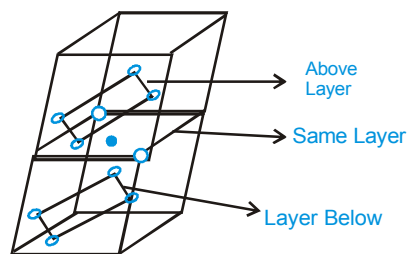
86. Total positive charge = Charge on Mg^{2+} + Charge on

$$\text{Al}^{3+} = \frac{1}{8} \times 8 \times 2 + \frac{1}{2} \times 4 \times 3 = 8 \text{ electronic charge.}$$

EXERCISE - 2

Part # I : Multiple Choice

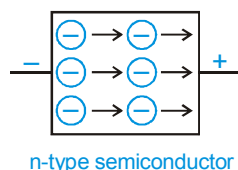
1. Randomness (entropy) in amorphous solids is more than that in crystalline solids.
3. Fcc can be viewed in two following ways -
 - (i) Planes along the faces (and parallel to it) of the unit cell.
 - \Rightarrow Each atom touches 4 in same layer, 4 in layer above and 4 in layer below it.
 - (ii) Planes along closest packed spheres \rightarrow each atom touches 6 atom in same layer, 3 in layer above and 3 in layer below it.



5. When silicon is doped with some group-15 element, the some of the positions in the lattice are substituted by atoms of groups -15 elements have five valence electrons. After forming the four covalent bonds with silicon

(or any other group-14 element such as germanium). One excess electron is left on them.

Since this electron is not involved in bonding it becomes delocalized and contribute to electrical conduction. Silicon doped with group 15 element behaves as a n-type semiconductor.



$$6. \text{ Density} = \frac{Z \times M}{N_A \times \text{volume}}$$

$$\text{so, Volume} = \frac{4 \times 207}{6.02 \times 10^{23} \times 11.34} = 1.213 \times 10^{-22} \text{ cm}^3$$

$$4r = a\sqrt{2}$$

$$r = \frac{4.95 \times 10^{-8} \times \sqrt{2}}{4} = 175 \text{ pm}$$

$$\text{Volume} = a^3 = 1.213 \times 10^{-22}$$

$$\text{so, } a = (1.213 \times 10^{-24})^{1/3}$$

$$a = 4.95 \times 10^{-8} \text{ cm.}$$

7. Na^+ & F^- are isoelectronic hence they will have same screening const (s) but not the effective nuclear charge.

$$\text{and } r_{\text{Na}^+} + r_{\text{F}^-} = 2.31 \text{ \AA} \text{ and } r_{\text{F}^-} = 1.36 \text{ \AA}$$

$$\therefore r_{\text{Na}^+} / r_{\text{F}^-} \approx 0.7$$

(coordination = 6, rock salt structure)

8. Schottky defect is only observed in ionic compound.
9. Ferrimagnetic substances lose ferrimagnetism on heating and become paramagnetic. In ferromagnetic substances all the domains get oriented in the direction of magnetic field and remain as such even after removing magnetic field.

Part # II : Assertion & Reason

- In HCP structure corner atom contribution is $\left(\frac{1}{6}\right)$.
- Zinc oxide losses oxygen reversible at high temperature and turn yellow.
- Based on radius ratio.
- There is both a vacancy and an interstitial ion.
- In these defects stoichiometry of compound maintained.
- In schottky defect density decreases while interstitial defect density increases.

EXERCISE - 3

Part # I : Matrix Match Type

1. (A) ZnS crystal $\begin{cases} \rightarrow \text{Zinc blende} \rightarrow \text{fcc} \\ \rightarrow \text{Wurtzite} \rightarrow \text{hcp} \end{cases}$

S^{2-} ion are present in fcc lattice & Zn^{2+} ion occupy all the tetrahedral voids distance of tetrahedral voids

$$\text{from corner} = \frac{\sqrt{3}a}{4}$$

- (B) $\text{CaF}_2 \rightarrow$ Fluorite structure

Ca^{2+} ion are present in ccp lattice & F^- ion are present in all tetrahedral voids.

- (C) $\text{NaCl} \rightarrow$ Rock salt Type structure

Cl^- ion are present in ccp lattice & Na^+ ion occupy all the octahedral voids.

- (D) Diamond crystal \rightarrow C atom present in fcc lattice in which alternate tetrahedral voids are occupied by C atom.

Part # II : Comprehension

Comprehension # 1 :

- On heating, $\text{ZnO}_{(s)}$ dissociates reversibly as
$$\text{ZnO} \rightleftharpoons \text{Zn}^{2+} + \frac{1}{2} \text{O}_2 + 2e^-$$
 Zn^{2+} ions occupy certain interstitial sites whereas the electrons released are present at the neighbouring sites, which act as F-centers.
- In the crystallization, some Ag^+ ions will get replaced by as many half of Cd^{2+} ions. Thus the cation vacancies will be the same as the number of Cd^{2+} is ions incorporated.

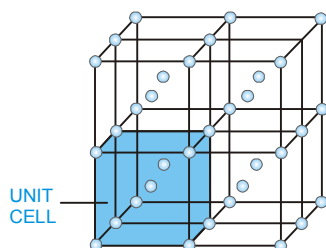
Comprehension # 2 :

- No. of X = $8 \times \frac{1}{8} + 6 \times \frac{1}{2} = 4 \Rightarrow 4 \text{ XY unit per cell.}$
No. of Y = $1 + 12 \times \frac{1}{4} = 4$
- At edge center, there is octahedral void in f.c.c. lattice.
 \Rightarrow C.N. of Y = 6
(6 : 6) C.N. \Rightarrow NaCl Structure.

EXERCISE - 4
Subjective Type

1. Number of atom effectively present in a cubic unit formed by arrangement of eight B.C.C unit cell

$$= 8 \times \frac{1}{8} + 12 \times \frac{1}{4} + 6 \times \frac{1}{2} + 1 + 8 = 16.$$



2. $n = 8, p = \frac{11}{21}$

3. Density (d) = $2 = \frac{2 \times M}{(3)^3}$ $M = 27$ amu

Then No. of atoms present in 243×10^{24} amu is

$$\Rightarrow \frac{243 \times 10^{24}}{27} = 9 \times 10^{24}$$

4. Ionic – NaCl, ZnSO₄ Metallic – Bronze, Fe
Molecular – S₈, I₂
Network – SiO₂, Diamond, Si Amorphous – Rubber, Glass

5. (a) Number of atoms in 2D unit cells = $\frac{1}{3} \times 6 + 1 \times 1 = 3.$

(b) Packing efficiency (of 2 layers)
$$= \frac{\text{Number of atoms} \times \text{Volume of 1 atom}}{\text{Total volume of 2 layers of unit cells}} \times 100$$

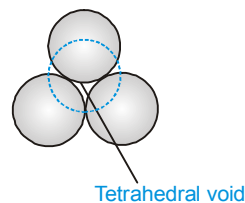
$$\text{Packing efficiency} = \frac{3 \times \frac{4}{3} \pi r^3}{\text{area of hexagon} \times \text{height}} \times 100$$

$$= \frac{3 \times \frac{4}{3} \pi r^3}{6 \times \frac{\sqrt{3}}{4} \times (2r)^2 \times (2r)} \times 100 = 60.43\%.$$

6. (i) $r^2\sqrt{3}$; (ii) $2r\sqrt{2/3}$; (iii) Yes, of course

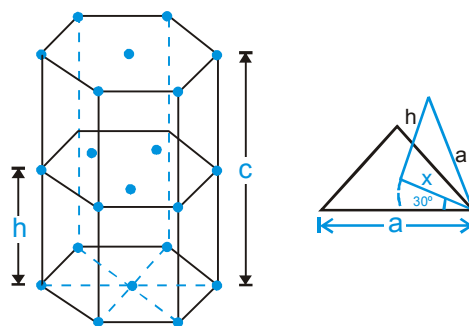
7. (a) 4.50 Å, (b) 5.20 Å, (c) 12, (d) 6, (e) 0.925 g/cm³

8. It is formed by four spheres the centres of which form a regular tetrahedron.



9. (i)
- | | Octahedral void | Tetrahedral void |
|-----|-----------------|------------------|
| HCP | 6 | 12 |
| FCC | 4 | 8 |
- (ii) False

10. Calculation of c.



$$\cos 30^\circ = \frac{a}{2 \times x} \quad \text{so } x = \frac{2a}{2 \times \sqrt{3}} = \frac{a}{\sqrt{3}}$$

Applying pythagoras theorem : $x^2 + h^2 = a^2$

$$\text{so } h^2 = a^2 - x^2 = a^2 - \frac{a^2}{3} = \frac{2}{3} a^2 \quad \text{and}$$

$$h = \sqrt{\frac{2}{3}} a = 2 \sqrt{\frac{2}{3}} r.$$

$$\text{so height of hexagon } c = 2h = 2 \sqrt{\frac{2}{3}} a.$$

11. Density of hcp = $\frac{Z \times M}{N_A \times (\text{Volume of unit cell})}$

$$\text{Volume of unit cell} = 6 \times \frac{\sqrt{3}}{4} a^2 \times C$$

$$= \frac{6 \times 1.732}{4} \times 295.5 \times 295.5 \times 472.9 \times 10^{-30}$$

$$= 107.281 \times 10^{-24} \text{ cm}^3.$$

$$\text{density} = \frac{6 \times 47.8}{6.023 \times 10^{-23} \times 107.281 \times 10^{-24}} = 4.438 \text{ g/cm}^3.$$

12. (a) Fe_2O_3 , (b) CdI_2 13. (a) 2.878 \AA , (b) 12, (c) 19.4 g/cm^3 , (d) 0.7405

14. Edge length $a = 500 \text{ pm} = 500 \times 10^{-10} \text{ cm}$
 Volume, $a^3 = (500 \text{ pm} = 500 \times 10^{-10} \text{ cm})^3 = 12.5 \times 10^{-23} \text{ cm}^3$.
 For fcc structure, number of atoms per unit cell, $Z = 4$
 Atomic mass, $M = 98.5 \text{ g}$
 density, $r = 5.22 \text{ g cm}^{-3}$
 We know that :

$$\text{Avogadro constant, } N_0 = \frac{M \times Z}{a^3 \times \rho} = \frac{98.5 \times 4}{12.5 \times 10^{-23} \times 5.22} = 6.038 \times 10^{23} \text{ atoms mol}^{-1}.$$

15. (a) XY_3 , (b) (i) X_7Y_{24} , (ii) XY_4 , (iii) $\text{X}_7\text{Y}_{24}\text{Z}$ 16. $N_A = 6.04 \times 10^{23}$

17. Number of octahedral void in ccp = Z ;
 Number of tetrahedral void in ccp = $2Z$.
 For A_2B , Number of anion $\text{B} = 4$.
 Cation (A) present in all octahedral void (100% occupied)
 and half tetrahedral void (50% occupied), then number

$$\text{of cation (A) in unit cell} = 4 + 8 \times \frac{1}{2} = 8.$$

So, formula of compound = A_2B .18. 4 Fe^{2+} & 4 O^{2-}

19. In ferromagnetic substance the magnetic moment is aligned spontaneously in one direction under the influence of external magnetic field and they become permanently magnetised. When magnetic moments are aligned in parallel and antiparallel directions in unequal numbers resulting net magnetic moment it is called ferrimagnetism.

20. In Silicon, electrons are fixed in covalent bonds and are not free for conduction, hence it is an insulator. On heating some of covalent bonds break and released excited electrons which can move under the electric field, and thus make the silicon, semiconductor.

21. No. of Mg^{2+} per unit cell = $8 [\text{At corners}] \times \frac{1}{8} = 1$

$$\text{No. of Ti per unit cell} = 1 [\text{body center}] \times \frac{1}{1} = 1$$

$$\text{No of O per unit cell} = 6 [\text{Face center}] \times \frac{1}{2} = 3$$

so formula = MgTiO_3
 atom are removed along face diagonal

$$\text{No. of } \text{Mg}^{2+} = 6 [\text{At corner}] \times \frac{1}{8} = \frac{6}{8} = \frac{3}{4}$$

$$\text{No. of Ti per unit cell} = 1 [\text{Body center}] \times \frac{1}{1} = 1$$

$$\text{No. of O per unit cell} = 6 [\text{Face center}] \times \frac{1}{2} = \frac{6}{2} = 3$$

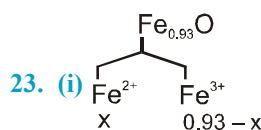
$$\text{So formula of compound} = \text{Mg}_{\frac{3}{4}}\text{TiO}_{\frac{5}{2}}$$

$$\begin{aligned} \text{Formula mass} &= 24 \times \frac{3}{4} + 48 + 16 \times \frac{5}{2} = 18 + 48 + 40 \\ &= 106 \text{ amu} \end{aligned}$$

As corner ion are touching so $a = 2 r_{\text{Mg}^{2+}} = 2 \times 0.7 = 1.4 \text{ \AA}$

$$d = \frac{\text{mass}}{\text{Volume}} = \frac{106 \times 1.67 \times 10^{-24}}{(1.4)^3 \times 10^{-24}} \text{ g/cm}^3 = 64.5 \text{ g/cm}^3$$

22. When the atoms or ions are missed or misplaced in the crystal, the defects are called point defects.



by charge balancing

$$2x + 3 [0.93 - x] = x$$

$$x = 2.79 \text{ so } \text{Fe}^{3+} = 0.14$$

In 0.1 mole compound $\text{Fe}^{2+} = 0.279$ & $\text{Fe}^{3+} = 0.014$

No. of vacancies = 0.007 mole

$$= 0.007 \times 6.02 \times 10^{23} \text{ vacancies.}$$

(ii) No. of Fe^{2+} ion = 0.079 mole which are replaced by Sn^{4+} with each replacement one vacancies is created.So no. of vacancies due to replacement of Fe^{2+} by Sn^{4+}

$$= \frac{0.079}{2} \text{ mole} = \frac{0.079}{2} = 0.0395 \text{ mole}$$

Total vacancies = $[0.007 + 0.0395] \text{ mole}$

$$= 0.0465 \times 6.02 \times 10^{23} \text{ vacancies}$$

24. (a) volume occupied by N_A unit cells

$$= \frac{\text{mass of } N_A \text{ unit cells}}{\text{density}} = \frac{168.5}{3.988} = 42.25 \text{ cm}^3$$

$$\begin{aligned} \text{so volume of one unit cell} &= \frac{42.25}{6.02 \times 10^{23}} \\ &= 7.014 \times 10^{-23} \text{ cm}^3 \end{aligned}$$

(b) smallest Cs – Cs distance = $a = (\text{volume})^{1/3}$
 $= (7.014 \times 10^{-23})^{1/3} = 4.125 \text{ \AA}$ (c) smallest Cs – Cl distance = $\frac{a\sqrt{3}}{2} = \frac{4.125\sqrt{3}}{2} = 3.572 \text{ \AA}$.

CHEMISTRY FOR JEE MAIN & ADVANCED

25. For simple cubic lattice

$$2(R+r) = a\sqrt{3} = 2R\sqrt{3} \quad [\text{for simple cubic lattice } a=2R]$$

$$R = \frac{r}{(\sqrt{3}-1)} = \frac{10}{(\sqrt{3}-1)} \text{ \AA}$$

$$\text{Then volume} = a^3 = (2R)^3 = \left(\frac{2 \times 10}{(\sqrt{3}-1)} \right)^3 = 1000(\sqrt{3}+1) \text{ \AA}^3$$

26. Volume of one unit cell = $a^3 = (288 \times 10^{-10})^3 \text{ cm}^3$

$$\text{Volume of 208 g of element} = \frac{\text{mass}}{\text{density}} = \frac{208}{7.2} = 28.88 \text{ cm}^3$$

$$\begin{aligned} \text{so no. of unit cells in this volume} &= \frac{28.88}{[2.88 \times 10^{-8}]^3} \\ &= 12.09 \times 10^{23} \text{ unit cells} \end{aligned}$$

Since $Z = 2$

$$\text{so Total no. of atoms} = 2 \times 12.09 \times 10^{23} = 24.18 \times 10^{23}.$$

27. $d = \frac{\text{mass}}{\text{volume}}$

For orthorhombic volume = $(a \times b \times c)$

$$\begin{aligned} &= \frac{128 \times 32 \times 1.67 \times 10^{-24}}{[10.46 \times 12.87 \times 24.49] \times 10^{-24}} \text{ gram/cm}^3 \\ &= 2.075 \text{ gram/cm}^3 \end{aligned}$$

28. Al_2O_3 – ionic

Br_2 – vanderwaal

F_2 – vanderwaal

ICl – dipole dipole

H_2O – dipole - dipole (H-bonding)

NaCl – ionic,

$$\text{F}_2 < \text{Br}_2 < \text{ICl} < \text{H}_2\text{O} < \text{NaCl} < \text{Al}_2\text{O}_3$$

29. $d = \frac{Z \times M}{6.02 \times 10^{23} \times [a \times b \times c]}$

$$1.419 = \frac{2 \times M}{6.02 \times 10^{23} \times [12.05 \times 15.05 \times 2.69] \times 10^{-24}} \text{ gram/cm}^3$$

$$\Rightarrow M = 208.4 \text{ gram/mol.}$$

30. $a^3 = \frac{Z \times M}{N_A \times d} = \frac{2 \times 183.9}{6.02 \times 10^{23} \times 19.3}$

$$\text{so } a = 3.16 \text{ \AA}$$

$$\text{now length of the body diagonal} = a\sqrt{3} = 5.48 \text{ \AA.}$$

31. Actual given density = $\frac{2}{3} \text{ amu} / \text{ \AA}^3$

$$\begin{aligned} \text{Density when 100\% solid Ar filled} &= \frac{40}{\frac{4}{3}\pi \times \left(\frac{3}{\pi^{1/3}}\right)^3} \\ &= \frac{40}{36} \text{ amu} / \text{ \AA}^3 \end{aligned}$$

$$\begin{aligned} \text{then \% of solid Ar without anything} &= \left(\frac{\frac{40}{36}}{\left(\frac{40}{36}\right)} \right) \times 100 \\ &= 40\% \text{ Ans.} \end{aligned}$$

32. $\frac{72.36}{56}$ 'Fe', $\frac{27.64}{16}$ 'O' \Rightarrow 1.292 'Fe', 1.7275 'O'

Hence proportion is 1 : 1.33 ;

So Empirical formula is Fe_3O_4 ,

Empirical formula mass = 232 amu

Now if there are x formula units in the unit cell

$$5.2 = \frac{x(232)}{(8.39 \times 10^{-8})^3} \Rightarrow x = 7.968 \approx 8$$

Hence number of ions in the unit cell = 56

33. Perimeter = $2a + \sqrt{2} a$

$$= 2[2(R+r)] + 4R = 4[r+2R]$$

34. Number of Au atoms in unit cell = $\frac{1}{8} \times 8 = 1$

$$\text{Number of Cd atoms in unit cell} = \frac{1}{2} \times 6 = 3$$

The formula the alloy will be AuCd_3 .

35. $d_{\text{fcc}} = \frac{Z_{\text{fcc}} \times M}{N_0 \times (a_{\text{fcc}})^3} = \frac{4 \times M}{N_0 \times (a_{\text{fcc}})^3}$

$$\Rightarrow d_{\text{BCC}} = \frac{Z_{\text{BCC}} \times M}{N_0 \times (a_{\text{bcc}})^3} = \frac{2 \times M}{N_0 \times (a_{\text{bcc}})^3}$$

$$\frac{d_{\text{fcc}}}{d_{\text{BCC}}} = 2 \left[\frac{a_{\text{bcc}}}{a_{\text{fcc}}} \right]^3$$

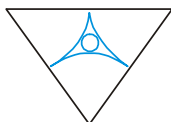
According to question $\sqrt{2} a_{\text{fcc}} = \sqrt{3} a_{\text{bcc}}$

$$= \left(\frac{a_{\text{bcc}}}{a_{\text{fcc}}} \right) = \left(\frac{\sqrt{2}}{\sqrt{3}} \right)$$

$$\Rightarrow \frac{d_{\text{fcc}}}{d_{\text{BCC}}} = 2 \left[\frac{\sqrt{2}}{\sqrt{3}} \right]^3 = 1.09.$$

36. Octahedral void is present at the body center, which is formed by six face centered atoms.

$$37. \text{Packing fraction} = \frac{\frac{1}{2}\pi R^2 + \pi (0.155R)^2}{\frac{1}{2}(2R)^2 \frac{\sqrt{3}}{2}} \times 100 = 95\%$$



38. (a) For titanium hydride
 No. of Ti atom per unit cell = 4
 No. of H atom = 8 [in tetrahedral voids] $\times 1 = 8$.
 So formula of compound = Ti_4H_8 or TiH_2
 For titanium carbide
 No. of Ti atom per unit cell = 4
 No. of C atom per unit cell = 4 [in octahedral voids] $\times 1 = 4$.
 So formula of compound = $\text{Ti}_4\text{C}_4 = \text{TiC}_4$

(b) For tetrahedral void. $\frac{r_{\text{H}}}{r_{\text{Ti}}} = 0.225$

(c) For octahedral void $\frac{r_{\text{C}}}{r_{\text{Ti}}} = 0.414$

- (d) The void occupied by small size particle is depends on radius ratio. As per radius ratio H atom occupy tetrahedral void not octahedral void.

39. $P_{\text{CO}_2} \times 9.56 = \left[\frac{39.6}{44} \right] \times 0.082 \times 373$

$P_{\text{CO}_2} = 2.88$

$(P_{\text{A}})_{\text{gas}} = 0.32$

For A- gas $\rightarrow P_{\text{A}} \times V = nRT$
 $= 0.32 \times 9.56 = n_{\text{A}} \times 0.082 \times 373$

$n_{\text{gas}} = 0.1 \text{ mole.}$

so molar mass of A = 254.5

Again $d_{\text{A}} = \frac{Z \times M}{N_0 \times a^3}$

$a^3 = \frac{4 \times 254.5}{6.02 \times 10^{23} \times 2.3}$

$a^3 = 735.2 \times 10^{-24}$

$a = 9 \times 10^{-8}$

$4r = \sqrt{2} a$

For FCC lattice

$r = \frac{\sqrt{2}}{4} a = 3.19 \times 10^{-8} \text{ cm.}$

$b = 4 \left[\frac{4}{3} \pi r^3 \right] \times N_{\text{A}} = 4 \times \frac{4}{3} \times 3.14 [3.19]^3 \times 10^{-24} \times 6.02 \times 10^{23}$
 $= 327.26 \text{ cm}^3/\text{mole.}$

40. $a = 2R, c = \sqrt{\frac{2}{3}} 2a = \sqrt{\frac{2}{3}} 4r$

41. $d = \frac{Z \times M}{N_0 \times \text{Volume}} \Rightarrow 0.92 = \frac{Z \times 18}{6.02 \times 10^{23} \left[\frac{6\sqrt{3}a^2}{4} \times c \right]}$

$\Rightarrow 0.92 = \frac{Z \times 18}{6.02 \times 10^{23} \left[\frac{6\sqrt{3}}{4} \times (4.53)^2 \times 7.41 \times 10^{-24} \right]}$

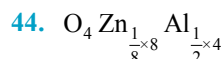
$\Rightarrow Z = 4.$

42. (a) Distance = $\frac{a\sqrt{3}}{2} = \frac{387 \times \sqrt{3}}{2} = 335.15 \text{ pm}$

(b) $r_{\text{NH}_4^+} = 335.15 - 181 = 154.15 \text{ pm.}$

43. (a) $d_{\text{c-c}} = \frac{1}{2} \times \sqrt{3} \cdot \frac{a_{\text{fcc}}}{2} = 154.4 \text{ pm}$

(b) fraction = $\frac{8 \times \frac{4}{3} \pi \left(\frac{d_{\text{c-c}}}{2} \right)^3}{a^3} = 0.34$



So, formula is ZnAl_2O_4 .

45. (a) As each Zn^{2+} ion is present in tetrahedral void. So it is coordination number is = 4.

- (b) Similarly S^{2-} ion have coordination number = 4.

- (c) As Zn^{2+} ion is present in tetrahedral void that's why line's connecting any two nearest neighbour and Zn^{2+} have angle = $109^\circ 28'$.

(d) For tetrahedral voids radius ratio is $\frac{r_{\text{Zn}^{2+}}}{r_{\text{S}^{2-}}} = 0.225.$

46. $r_+ + r_- = \frac{a}{2} \Rightarrow \frac{3r_+}{2} = \frac{a}{2}; r_- = \frac{a}{3}$ and $r_+ = \frac{a}{6}$

Packing fraction = $\frac{4 \times \frac{4}{3} \pi (r_+^3 + r_-^3)}{a^3}$
 $= \frac{4 \times \frac{4}{3} \pi \left[\left(\frac{a}{6} \right)^3 + \left(\frac{a}{3} \right)^3 \right]}{a^3} = 0.7.$

Percentage void = 30%.

$$47. \frac{r_+}{r_-} = \frac{1.6}{1.864} = 0.858$$

So, it is CsCl type unit cell

$$\text{So } \sqrt{3} a = 2(r_+ + r_-)$$

$$\text{So } a = \frac{2(1.864 + 1.6)}{\sqrt{3}} \text{ \AA} = 2 \times 2 \text{ \AA} = 4 \text{ \AA}$$

$$48. \text{ No. of Sr atom per unit cell} = 8 [\text{corner}] \times \frac{1}{8} = 1$$

$$\text{No. of Ti atom per unit cell} = 1 [\text{center}] \times 1 = 1$$

$$\text{No. of O atom per unit cell} = 6 [\text{face center}] \times \frac{1}{2} = 3$$

So formula of compound SrTiO_3

Edge length = 391 pm.

(a) Ti atom is present at body center of fcc lattice which act as octahedral voids. Which has coordination number = 6.

(b) Sr atom is present at corner of fcc lattice with has coordination number = 12.

$$(c) \text{ density} = d = \frac{Z \times M}{N_0 \times a^3} = \frac{184}{6.02 \times 10^{23} \times (3.91 \times 10^{-8})^3} = 5.1 \text{ gram/cc.}$$

(d) In fcc lattice distance of nearest neighbour of Sr atom

$$= \frac{\sqrt{2}a}{2} = \frac{a}{\sqrt{2}} = 276.5 \text{ pm.}$$

49. (i) In schottky defects density decreases.

(ii) In interstitial defects density increases.

(iii) In frenkel defects density remain same.

$$50. \quad 2(1-x)/(3x-2) \quad \begin{array}{c} \xrightarrow{M_x} \\ M^{2+} \quad M^{3+} \\ (\text{Let } y) \quad = x-y \end{array}$$

$$\Rightarrow \text{Applying charge balance, } 2y + 3(x-y) - 2 = 0$$

$$\Rightarrow y = 3x - 2$$

$$\therefore \frac{M^{3+}}{M^{2+}} = \frac{x-y}{y} = \frac{x-(3x-2)}{3x-2} = \frac{-2x+2}{3x-2}$$

$$= \frac{2(1-x)}{(3x-2)}$$

EXERCISE - 5

Part # 1 : AIEEE/JEE-MAIN

1. When an atom or ion is missing from its normal lattice site, a lattice vacancy is created. This defect is known as Schottky defect. Here equal number of Na^+ and Cl^- ions are missing from their regular lattice position in the crystal. So it is Schottky defect.

2. Number of A ions per unit cell = $\frac{1}{8} \times 8 = 1$; Number of B

$$\text{ions per unit cell} = \frac{1}{2} \times 6 = 3$$

Empirical formula = AB_3 .

3. In case of a face-centered cubic structure, since four atoms are present in a unit cell, hence volume.

$$V = 4 \left(\frac{4}{3} \pi r^3 \right) = \frac{16}{3} \pi r^3$$

4. According to question :

$$\text{Number of Y atom in ccp unit cell} = 4$$

$$\text{Number of X atom in ccp unit cell} = 8 \times \frac{2}{3} = \frac{16}{3}$$

$$\text{Formula of compound} = \text{X}_{\frac{16}{3}}\text{Y}_4 = \text{X}_{16}\text{Y}_{12} = \text{X}_4\text{Y}_3$$

5. In fcc unit cell $4r = \sqrt{2}a$

[r = radius of Cu atom, a = edge length]

$$\text{So } r = \frac{\sqrt{2}a}{4}$$

$$r = \frac{\sqrt{2} \times 361}{4} = 127 \text{ pm.}$$



$$2 \times 110 + 2 \times r_- = 508$$

$$2r_- = 288$$

$$r_- = 144 \text{ pm}$$

$$7. \text{ Packing fraction of CCP} = \frac{\pi}{3\sqrt{2}} = 0.74 \Rightarrow 74\%$$

$$\therefore \text{Percentage of free space in CCP} = 100 - 74 = 26\%$$

$$\text{Packing fraction of BCC} = \frac{\pi\sqrt{3}}{8} = 0.68 \Rightarrow 68\%$$

$$\therefore \text{Percentage of free space in BCC} = 100 - 68 = 32\%$$

$$8. \quad \text{A}_{8 \times \frac{1}{8}} \text{B}_{5 \times \frac{1}{2}}$$

Formula of compound A_2B_5 .

9. FCC lattice

$$a = 361 \text{ pm}$$

$$a\sqrt{2} = 4r$$

$$r = \frac{361 \times \sqrt{2}}{4} = 127.6 \approx 128 \text{ pm.}$$

10. For BCC structure
- $\sqrt{3} a = 4r$

$$r = \frac{\sqrt{3}}{4} a = \frac{\sqrt{3}}{4} \times 351 = 152 \text{ pm.}$$

11. In FCC unit cell atoms are in constant along face diagonal.

$$\text{So, } \sqrt{2} a = 4R$$

$$\therefore \text{ closest distance } (2R) = \frac{\sqrt{2} a}{2} = \frac{a}{\sqrt{2}}$$

12. In Frenkel defect, some of iron (usually cation due to their small size) missing from their correct position and occupies position in interstitial.

Part # II : IIT-JEE ADVANCED

1. (a) $\frac{a}{2} = Y^{\frac{1}{3}}$

$$a = 2Y^{\frac{1}{3}}$$

$$\text{density (d)} = \frac{4 \times 6.023 \times Y \times 10^{-3}}{6.023 \times 10^{23} (2Y^{\frac{1}{3}} \times 10^{-9})^3} = 5.0 \text{ Kg/M}^3$$

- (b) Observed density of AB is 20 Kg/M
- ³

Which is Higher then calculate density 5kg/m³ thus AB has either interstitial impurity defect or substitutional impurity defect.

2. In cubic close packing no. of tetrahedral void = 2 × no of atom. As there are 4 S
- ²⁻
- ions at lattice point and they need 4 Zn
- ²⁺
- , which adjusted in alternate tetrahedral

$$\text{void } (0.225 < \frac{r^+}{r^-} < 0.414).$$

3. For f.c.c.
- $\left(\frac{r_1}{r_2} = 0.414 \right)$
- octahedral void

$$\frac{r_1}{r_2} = 0.225 \text{ Tetrahedral void}$$

We know along face diagonal for f.c.c. $4r_2 = a\sqrt{2}$

$$\Rightarrow r_2 = \frac{a\sqrt{2}}{4}$$

required diameter of interstitial sites = $2r_1 = 2 \times 0.414r_2$

$$\text{Diameter} = \frac{2 \times .414 \times \sqrt{2} \times a}{4} = \frac{2 \times .414 \times \sqrt{2} \times 400}{4} = 117.1 \text{ pm.}$$

4. $d = \frac{ZM}{N_A a^3} \Rightarrow Z = 20 \times 10^{-1} = 2$

So its is a bcc unit cell. Hence $\sqrt{3} a = 4R$

$$\text{so } R = \frac{\sqrt{3}}{4} \times 5\text{\AA} = 216.5 \text{ pm.}$$

5. (A) Simple cubic and fcc (i) have the cell parameters
- $a = b = c$
- &
- $\alpha = \beta = \gamma$
- (choice P) and belong to the same crystal system (choice (s)).

(B) Cubic & rhombohedral (i) have the cell parameters $a = b = c$ and $\alpha = \beta = \gamma$ (choice P) and (ii) are two crystal systems (choice (q)).

(C) Cubic and tetragonal are two crystal system (q).

(D) Hexagonal & monocubic (i) two crystal system choice (q) p (ii) have only two crystallographic angles of 90° choices.

6. Total no. of atoms in 1 unit cell = $\left(12 \times \frac{1}{6} \right) + 3 + \left(2 \times \frac{1}{2} \right) = 6$

7. $C = \sqrt{\frac{2}{3}} 4r = \text{Height of the unit cell.}$

$$\text{Base area} = 6 \times \frac{\sqrt{3}}{4} (2r)^2.$$

$$\text{Volume of the hexagon} = \text{Area of base} \times \text{Height} = 6.$$

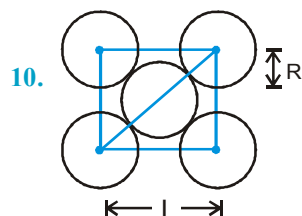
$$\frac{\sqrt{2}}{3} a^2 \times c = 4r^2 \times \frac{\sqrt{2}}{3} 4r = 24 \sqrt{2} \cdot r^3$$

8. Packing fraction = $\frac{\text{volume of the atoms in one unit cell}}{\text{volume of one unit cell}}$

$$= \frac{6 \times \frac{4}{3} \pi r^3}{24 \sqrt{2} r^3} = \frac{\pi}{3\sqrt{2}} = 0.74 = 74\%$$

$$\Rightarrow \text{empty space} = 100 - 74 = 26\%.$$

9. Frenkel defect is a dislocation defect. Trapping of an electron in the lattice leads to the formation of F-center.



$$4R = L\sqrt{2}$$

$$\text{so, } L = 2\sqrt{2}R$$

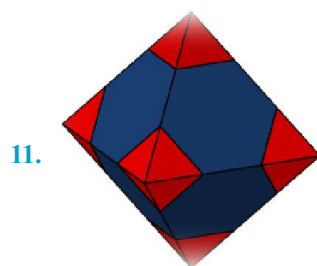
$$\text{Area of square unit cell} = (2\sqrt{2}R)^2 = 8R^2$$

Area of atoms present in one unit cell

$$= \pi R^2 + 4\left(\frac{\pi R^2}{4}\right) = 2\pi R^2$$

$$\text{so, packing efficiency} = \frac{2\pi R^2}{8R^2} \times 100$$

$$= \frac{\pi}{4} \times 100 = 78.54\%$$



12. No. of M atoms = $\frac{1}{4} \times 4 + 1 = 1 + 1 = 2$

No. of X atoms = $\frac{1}{2} \times 6 + \frac{1}{8} \times 8 = 3 + 1 = 4$
 so formula = $M_2X_4 = MX_2$

13. 2

FCC $a = 400 \text{ pm}$

$$d_{\text{FCC}} = \frac{Z_{\text{FCC}} \times \text{GMM}}{N_A \times a^3}$$

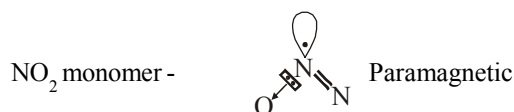
$$8 \text{ g/ml} = \frac{4 \times \text{GMM}}{N_A \times 64 \times 10^{-24}}$$

$$\text{GMM} = 128 \times N_A \times 10^{-24}$$

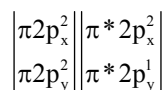
$$= \frac{N_A}{128 \times N_A \times 10^{-24}} \times 256$$

N = 2 Ans.

14. H atom : \uparrow - Paramagnetic



O₂ - (Superoxide) :- $\sigma 1s^2, \sigma^* 1s^2, \sigma 2s^2, \sigma^* 2s^2, \sigma 2p_z^2$



One unpaired electron is present in either $\pi^* 2p_x$ or $\pi^* 2p_y$. So it is paramagnetic in nature.

Dimetric sulphur in vapour phase :- It is similar as O₂ in vapour state, paramagnetic in nature.

Mn₃O₄ :- It is combined form of MnO and Mn₂O₃. Mn⁺² has 5 unpaired electrons (d⁵ electronic configuration)

Mn⁺³ has 4 unpaired electrons (d⁴ electronic configuration)

So it is paramagnetic in nature.

(NH₄)₂[FeCl₄]⁻² :- Consist [Fe⁺²Cl₄]⁻² ion.

[FeCl₄]⁻² tetrahedral, sp³ Hybridized, has configuration eg³, t₂g³. (Paramagnetic in nature)

(NH₄)₂[NiCl₄]⁻² :- Consist [Ni⁺²Cl₄]⁻² ion.

[NiCl₄]⁻² tetrahedral, sp³ Hybridized, has configuration eg⁴, t₂g³. (Paramagnetic in nature)

K₂MnO₄ :- Mn⁺⁶ is present in compound which has one unpaired electron in 3rd subshell. Mn⁺⁶ - [Ar]3d¹ Paramagnetic in nature.

K₂CrO₄ : Cr⁺⁶ is present in compound which has zero unpaired electron, diamagnetic in nature.

15. As per given information cation form FCC lattice and anion occupy all the octahedral void.

So	M ⁺	X ⁻	&	Formula MX
	4 ion	4 ion		
After step I	4 ion	1 ion		
After step II	1 ion	4 ion		
After step III	0 ion	4 ion		
After step IV	1 ion	3 ion		

$$\text{So ratio of } \frac{\text{No. of anion}}{\text{No. of cation}} = \frac{3}{1}$$

MOCK TEST

1. (A)

2. (D)

When all particle along body diagonal one removed, these 2 X atoms from corner are removed, one Y particle removed & 2 Z particle removed.

$$\text{Hence new arrangement, X particle} = \frac{1}{8} \times 6 + \frac{1}{2} \times 6 = \frac{15}{4}$$

; Y particle = 6; Z particle = 3

$$\text{Hence formula} = X_{\frac{15}{4}}Y_3Z_6 = X_{\frac{5}{4}}YZ_6 = X_6Y_4Z_8$$

3. (B)

From the sizes of octahedral and tetrahedral voids, it is clear that the atoms occupying these voids will not touch each other as we have along body diagonal of FCC.

4. (A)

$$d_{c-c} = \sqrt{\frac{1}{16} + \frac{1}{16} + \frac{1}{16}} = \sqrt{\frac{3}{16}} \quad \text{and } a_{\text{FCC}} = 1$$

5. (A)

6. (B)

7. (A)

Formula ZnAl_2O_4

Packing fraction

$$= \frac{\text{Total volume of particles present in one unit cell}}{\text{volume of one unit cell}}$$

$$= \frac{\left(\frac{4}{3}\pi r_{\text{Zn}^{2+}}^3\right) + \left(\frac{2 \times 4}{3}\pi r_{\text{Al}^{3+}}^3\right) + \left(\frac{4 \times 4}{3}\pi r_{\text{O}^{2-}}^3\right)}{a^3}$$

$$= \frac{\left(\frac{4}{3}\pi \frac{a^3(0.225)^3}{(2\sqrt{2})^3}\right) + \left(2 \times \frac{4}{3}\pi \frac{a^3(0.414)^3}{(2\sqrt{2})^3}\right) + \left(4 \times \frac{4}{3}\pi \frac{a^3}{(2\sqrt{2})^3}\right)}{a^3}$$

$$= 0.77$$

8. (D)

In 1 mole of M_xO ,

mole of M^{2+} ion = y

\therefore mole of M^{3+} = x - y.

Applying charge balance, $2y + 3(x - y) - 2 = 0$

$$\therefore \frac{\text{M}^{3+}}{\text{M}^{2+}} = \frac{x - y}{y} = \frac{x - (3x - 2)}{3x - 2} = \frac{(2x - 2)}{3x - 2} = \frac{2(x - 1)}{3x - 2}$$

9. (B, C)

From FCC unit cell

10. (C)

Atoms along one edge or at corners do not touch each other in FCC cell.

11. (ABCD)

12. (A)

13. (B)

Zinc oxide loses oxygen reversible at high temperature and turn yellow.

14. (A)

15. (C)

16. (A)

$$3x + (0.93 - x) \times 2 = 2$$

$$x = 0.14$$

$$\% \text{ of Fe as Fe (III)} = \frac{0.14}{0.93} \times 100 = 15\%$$

17. (A)

$$4 d_{c-c} \sin(54^\circ 44') = \sqrt{2} a \Rightarrow r = \frac{d_{c-c}}{2} = 0.78$$

18. (C)

$$d = \frac{8 \times 12}{N_A \times a^3} = 3.37 \text{ gm/cc.}$$

19. (C)

$$\text{Total number of unit cells} = \frac{1.2 \times N_A}{12 \times 8} = 7.5 \times 10^{21}.$$

20. [A \rightarrow p, q, s]; [B \rightarrow p, q, r]; [C \rightarrow s]; [D \rightarrow p, q, s].21. [A \rightarrow p, q, r, s]; [B \rightarrow p, r, s]; [C \rightarrow p, s]; [D \rightarrow p, r, s]

$$22. d = \frac{81 \times 2 \times 1000}{6 \times 10^{23} [4 \times 4 \times 5] \times 10^{-24}} \text{ mg/cc} = 375 \text{ mg/cc.}$$

23. Mass of 1 units cell = 4 × mass of 1 NaCl unit

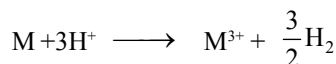
$$= 4 \times \frac{58.5}{6.022 \times 10^{23}} \text{ g} = 3.885 \times 10^{-22} \text{ g.}$$

$$\therefore \text{Number of unit cells per 1.0 g of NaCl} = \frac{1.0}{3.885 \times 10^{-22}}$$

$$= 2.57 \times 10^{21}$$

$$\text{No. of unit cells per edge} = \sqrt[3]{2.57 \times 10^{21}} = 1.37 \times 10^7.$$

$$24. (a) \text{ Moles of H}_2 \text{ gas} = \frac{701.1 \times 4}{760 \times 0.082 \times 300} = 0.15.$$



$$\therefore \text{moles of M used} = 0.1 = \frac{2.7 \times 1}{\text{atomic weight}}$$

⇒ Atomic weight of metal = 27 gm/mol.

∴ metal is Al.

$$(b) \text{ Density} = \frac{Z}{N_A} \left(\frac{M}{a^3} \right)$$

$$\Rightarrow 2.7 = \frac{Z}{6 \times 10^{23}} \left(\frac{27}{(405.5 \times 10^{-10})^3} \right)$$

⇒ Z = 4.

(c) For FCC unit cell, $4r = \sqrt{2} a$

⇒ r = 143.4 pm.

$$25. (a) n = \text{no. of moles} = \frac{PV}{RT} = \frac{12.5}{760} \times \frac{1}{2} \times \frac{1}{0.082 \times 1075}$$

$$= 9.318 \times 10^{-5}$$

$$\text{Number of atoms} = nN_A = 5.612 \times 10^{19}$$

$$\text{So number of unit cells} = \left(\frac{nN_A}{2} \right) = 2.806 \times 10^{19}$$

So, if there are x unit cells along one edge of given cube then

Then total number of unit cells in the cubic crystal

$$= x^3 = \frac{nN_A}{2} = 2.806 \times 10^{19} \quad \Rightarrow x = 3.04 \times 10^6$$

Now if edge length of unit cell = a ⇒ ax = 1.62 mm.

$$\Rightarrow a = 5.33 \times 10^{-9} \text{ mm} \Rightarrow a = 533 \text{ pm}$$

$$\therefore r = \frac{\sqrt{3}a}{4} = 230.8 \text{ pm}$$

(b) So metal must be potassium

$$(c) \rho_{\text{solid}} = \frac{2 \times 39}{6.022 \times 10^{23} \times a^3} = 0.86 \text{ gm/cm}^3$$

$$\rho_{\text{gas}} = \frac{PM}{RT} = \frac{12.5 \times 39}{760 \times 0.0821 \times 1075} = 7.27 \times 10^{-3} \text{ gm/cm}^3$$

Ans. (a) 231 pm, (b) K, (c) density of solid = 0.857 g/cc, density of vapour = 7.29 × 10⁻⁶ g/cc

$$26. \text{pH} = \frac{1}{2} \{ \text{pK}_w - \text{pK}_b - \log C \}$$

$$\Rightarrow 6 = 7.0 - \frac{5}{2} - \frac{1}{2} \log C \Rightarrow C = 0.01 \text{ M}$$

$$\therefore C = \frac{1.296}{\text{Molar mass}} = \frac{1}{100}$$

⇒ molar mass of salt = 129.6

$$\text{For rock salt, } 600\sqrt{2} = \sqrt{2} a$$

$$\therefore a = 600 \text{ pm} = 600 \times 10^{-10} \text{ cm.}$$

Now density

$$= \frac{Z}{N_A} \left(\frac{M}{a^3} \right) = \frac{4}{6.0 \times 10^{23}} \left[\frac{129.6}{(600)^3 \times 10^{-30}} \right] = 4 \text{ gm/cc.}$$

Ans. 4g/cc